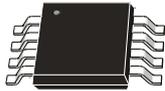
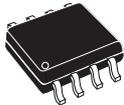


Very high accuracy (20 μ V), zero-drift, rail-to-rail output, 3 MHz, 36 V op amp



MiniSO8



SO8

Features

- Very low offset voltage: 20 μ V max. @ 25 °C
- Rail-to-rail output
- Wide supply voltage: 4 to 36 V
- Gain bandwidth product: 3 MHz
- Slew rate: 2 V/ μ s
- Low noise: 24 nV/ $\sqrt{\text{Hz}}$
- EMI hardened
- High ESD tolerance: 4 kV HBM
- Extended temperature range: -40 °C to 125 °C
- AEC-Q100 qualified

Applications

- Industrial
- Power supplies
- Automotive

Maturity status link

[TSB182](#)

Related products

TSB612	For lower current consumption
TSB622	For lower speed
TSB572	For rail-to-rail inputs
TSB712	For higher speed, precision, and rail-to-rail inputs

Description

The **TSB182** is a very high precision dual operational amplifier with a maximum guaranty of 20 μ V on input offset voltage. It can operate over an extended supply voltage operating range and features rail-to-rail output. It offers an excellent speed/power consumption ratio with 3 MHz gain bandwidth product while consuming 650 μ A typically per operational amplifier on a large supply voltage range.

The **TSB182** operates over a wide temperature range from -40 °C to 125 °C making this device ideal for industrial and automotive applications with the associated qualification.

Thanks to its small package size, the **TSB182** can be used in applications where space on the board is limited. It can thus reduce the overall cost of the PCB.

1 Pin description

Figure 1. Pin connections (top view)

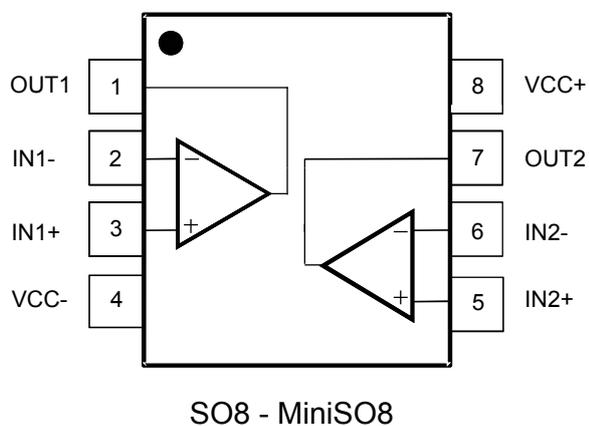


Table 1. Pin description

Pin	Pin name	Description
1	OUT1	Output
2	IN1 -	Negative input voltage
3	IN1 +	Positive input voltage
4	VCC -	Negative supply voltage
5	IN2 +	Positive input voltage
6	IN2 -	Negative input voltage
7	OUT2	Output
8	VCC +	Positive supply voltage

2 Absolute maximum ratings and operating conditions

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
Vcc	Supply voltage ⁽¹⁾	40	V
Vid	Differential input voltage ⁽²⁾	± 0.7	V
Vin	Input voltage	(Vcc-) -0.3 to (Vcc+) +0.3	V
Iin	Input current ⁽³⁾	10	mA
Tstg	Storage temperature	-65 to 150	°C
Tj	Junction temperature	150	°C
Rth-ja	Thermal resistance junction-to-ambient ^{(4) (5)}		°C/W
	SO8	125	
	MiniSO8	190	
ESD	Human Body Model (HBM) ⁽⁶⁾	4000	V
	Machine Model (MM) ⁽⁷⁾	200	
	Charged Device Model (CDM) ⁽⁸⁾	1500	

1. All voltage values, except differential voltage, are with respect to network ground terminal.
2. The differential voltage is the difference between inverting and non-inverting terminal voltage.
3. Input current must be limited by a resistor in series with the inputs.
4. Rth are typical values.
5. Short-circuits can cause excessive heating and destructive dissipation.
6. According to JEDEC standard JESD22-A114F.
7. According to JEDEC standard JESD22-A115A.
8. According to ANSI/ESD STM 5.3.1.

Table 3. Operating conditions

Symbol	Parameter	Value	Unit
Vcc	Supply voltage	4 to 36	V
Vicm	Common mode voltage on input pins	(Vcc-) to (Vcc+) -2	V
T	Operating free-air temperature range	-40 to 125	°C

3 Electrical characteristics

Table 4. Electrical characteristics $V_{CC} = 5\text{ V}$, $V_{icm} = V_{CC}/2$, $R_L = 10\text{ k}\Omega$ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V_{IO}	Input offset voltage	$V_{icm} = V_{CC}/2$				μV
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
		$V_{icm} = 0\text{ V}$				
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
$ \Delta V_{IO}/\Delta T $	Input offset voltage drift	$T_{min} < T < T_{max}$		30	100	$\text{nV}/^\circ\text{C}$
I_{IB}	Input bias current	$T = 25\text{ }^\circ\text{C}$			400	pA
		$T_{min} < T < T_{max}$			400	
I_{IO}	Input offset current	$T = 25\text{ }^\circ\text{C}$			600	pA
		$T_{min} < T < T_{max}$			600	
CMR	Common mode rejection ratio	$V_{icm} = 0\text{ to }V_{CC}-2\text{ V}$, $V_{out} = V_{CC}/2$	105	130		dB
		$T_{min} < T < T_{max}$	97			
Avd	Large signal voltage gain	$V_{OUT} = 0.5\text{ to } (V_{CC} - 0.5\text{ V})$	105	130		dB
		$T_{min} < T < T_{max}$	96			
V_{OL}	Output swing from negative rail	$T = 25\text{ }^\circ\text{C}$		30	50	mV
		$T_{min} < T < T_{max}$			80	
V_{OH}	Output swing from positive rail	$T = 25\text{ }^\circ\text{C}$		20	40	mV
		$T_{min} < T < T_{max}$			60	
I_{OUT}	Isink	$V_{OUT} = V_{OL}$				mA
		$T = 25\text{ }^\circ\text{C}$	20	27		
		$T_{min} < T < T_{max}$	10			
	Isource	$V_{OUT} = V_{OH}$				
$T = 25\text{ }^\circ\text{C}$		20	29			
I_{CC}	Supply current (per channel)	No load, $V_{OUT} = V_{CC}/2$		650	850	μA
		$T_{min} < T < T_{max}$			900	
AC performance						
GBP	Gain bandwidth product	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$	1.8	3		MHz
		$T_{min} < T < T_{max}$	1.6			
SR	Slew rate	$T = 25\text{ }^\circ\text{C}$	0.85	2		$\text{V}/\mu\text{s}$
		$T_{min} < T < T_{max}$	0.75			
Φ_m	Phase margin	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$		58		$^\circ$
Gm	Gain margin			15		dB
En	Equivalent input noise voltage	$f = 1\text{ kHz}$		27		$\text{nV}/\sqrt{\text{Hz}}$
		0.1 to 10 Hz		700		nVpp

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
THD+N	Total harmonic distortion + noise	$f = 1 \text{ kHz}$, $G = 1$, $V_{OUT} = 1 \text{ Vpp}$		0.005		%
Cs	Channel separation	$f = 1 \text{ kHz}$		130		dB
trec	Overload recovery time	$G = -10$		2		μs
Ts	Settling time	0.1% to final value, $G = 1$, 1 V step		18		μs
Cload	Capacitive load drive	No sustained oscillation		1		nF

Table 5. Electrical characteristics $V_{CC} = 12\text{ V}$, $V_{icm} = V_{CC}/2$, $R_L = 10\text{ k}\Omega$ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V_{IO}	Input offset voltage	$V_{icm} = V_{CC}/2$				μV
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
		$V_{icm} = 0\text{ V}$				
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
$ \Delta V_{IO}/\Delta T $	Input offset voltage drift	$T_{min} < T < T_{max}$		25	100	$\text{nV}/^\circ\text{C}$
I_{IB}	Input bias current	$T = 25\text{ }^\circ\text{C}$			400	μA
		$T_{min} < T < T_{max}$			400	
I_{IO}	Input offset current	$T = 25\text{ }^\circ\text{C}$			600	μA
		$T_{min} < T < T_{max}$			600	
CMR	Common mode rejection ratio	$V_{icm} = 0\text{ to }V_{CC} - 2\text{ V}$, $V_{OUT} = V_{CC}/2$	116	140		dB
		$T_{min} < T < T_{max}$	107			
Avd	Large signal voltage gain	$V_{OUT} = 0.5\text{ to } (V_{CC} - 0.5\text{ V})$	113	135		dB
		$T_{min} < T < T_{max}$	106			
V_{OL}	Output swing from negative rail	$T = 25\text{ }^\circ\text{C}$		60	90	mV
		$T_{min} < T < T_{max}$			120	
V_{OH}	Output swing from positive rail	$T = 25\text{ }^\circ\text{C}$		40	70	mV
		$T_{min} < T < T_{max}$			90	
I_{OUT}	Isink	$V_{OUT} = V_{OL}$				mA
		$T = 25\text{ }^\circ\text{C}$	20	26		
		$T_{min} < T < T_{max}$	10			
	Isource	$V_{OUT} = V_{OH}$				
$T = 25\text{ }^\circ\text{C}$		20	29			
I_{CC}	Supply current (per channel)	No load, $V_{OUT} = V_{CC}/2$		650	850	μA
		$T_{min} < T < T_{max}$			900	
AC performance						
GBP	Gain bandwidth product	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$	1.8	3		MHz
		$T_{min} < T < T_{max}$	1.6			
SR	Slew rate	$T = 25\text{ }^\circ\text{C}$	0.8	1.8		$\text{V}/\mu\text{s}$
		$T_{min} < T < T_{max}$	0.75			
Φ_m	Phase margin	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$		55		$^\circ$
Gm	Gain margin			12		dB
En	Equivalent input noise voltage	$f = 1\text{ kHz}$		25		$\text{nV}/\sqrt{\text{Hz}}$
		0.1 to 10 Hz		650		nV_{pp}
THD+N	Total harmonic distortion + noise	$f = 1\text{ kHz}$, Gain = 1, $V_{OUT} = 1\text{ V}_{pp}$		0.004		%
Cs	Channel separation	$f = 1\text{ kHz}$		130		dB

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
t_{rec}	Overload recovery time	G = -10		1		μs
T_s	Settling time	0.1% to final value, G = 1, 10 V step		7		μs
C_{load}	Capacitive load drive	No sustained oscillation		1		nF

Table 6. Electrical characteristics $V_{CC} = 36\text{ V}$, $V_{icm} = V_{CC}/2$, $R_L = 10\text{ k}\Omega$ connected to $V_{CC}/2$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
DC performance						
V_{IO}	Input offset voltage	$V_{icm} = V_{CC}/2$				μV
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
		$V_{icm} = 0\text{ V}$				
		$T = 25\text{ }^\circ\text{C}$	-20		+20	
		$T_{min} < T < T_{max}$	-30		+30	
$ \Delta V_{IO}/\Delta T $	Input offset voltage drift	$T_{min} < T < T_{max}$		20	100	$\text{nV}/^\circ\text{C}$
I_B	Input bias current	$T = 25\text{ }^\circ\text{C}$			500	μA
		$T_{min} < T < T_{max}$			500	
I_{IO}	Input offset current	$T = 25\text{ }^\circ\text{C}$			800	μA
		$T_{min} < T < T_{max}$			800	
CMR	Common mode rejection ratio	$V_{icm} = 0\text{ to }V_{CC} - 2\text{ V}$, $V_{OUT} = V_{CC}/2$	127	150		dB
		$T_{min} < T < T_{max}$	120			
SVR	Supply voltage rejection ratio	$V_{CC} = 4\text{ to }36\text{ V}$	127	138		dB
		$T_{min} < T < T_{max}$	120			
Avd	Large signal voltage gain	$V_{OUT} = 0.5\text{ to } (V_{CC} - 0.5\text{ V})$	124	145		dB
		$T_{min} < T < T_{max}$	115			
V_{OL}	Output swing from negative rail	$T = 25\text{ }^\circ\text{C}$		140	200	mV
		$T_{min} < T < T_{max}$			270	
V_{OH}	Output swing from positive rail	$T = 25\text{ }^\circ\text{C}$		130	200	mV
		$T_{min} < T < T_{max}$			300	
I_{OUT}	Isink	$V_{OUT} = V_{OL}$				mA
		$T = 25\text{ }^\circ\text{C}$	20	24		
		$T_{min} < T < T_{max}$	12			
	Isource	$V_{OUT} = V_{OH}$				
$T = 25\text{ }^\circ\text{C}$		20	27			
I_{CC}	Supply current (per channel)	No load, $V_{OUT} = V_{CC}/2$		670	850	μA
		$T_{min} < T < T_{max}$			900	
AC performance						
GBP	Gain bandwidth product	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$	1.8	3		MHz
		$T_{min} < T < T_{max}$	1.8			
SR	Slew rate	$T = 25\text{ }^\circ\text{C}$	0.8	1.7		$\text{V}/\mu\text{s}$
		$T_{min} < T < T_{max}$	0.6			
Φ_m	Phase margin	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$		54		$^\circ$
G_m	Gain margin			11		dB
E_n	Equivalent input noise voltage	$f = 1\text{ kHz}$		24		$\text{nV}/\sqrt{\text{Hz}}$
		0.1 to 10 Hz		620		nV_{pp}

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
THD+N	Total harmonic distortion + noise	$f = 1 \text{ kHz}$, $G = 1$, $V_{OUT} = 2 \text{ Vpp}$		0.002		%
C_s	Channel separation	$f = 1 \text{ kHz}$		130		dB
t_{rec}	Overload recovery time	$G = -10$		1		μs
T_s	Settling time	0.1% to final value, $G = 1$, 10 V step		7		μs
C_{load}	Capacitive load drive	No sustained oscillation		1		nF

4 Typical performance characteristics

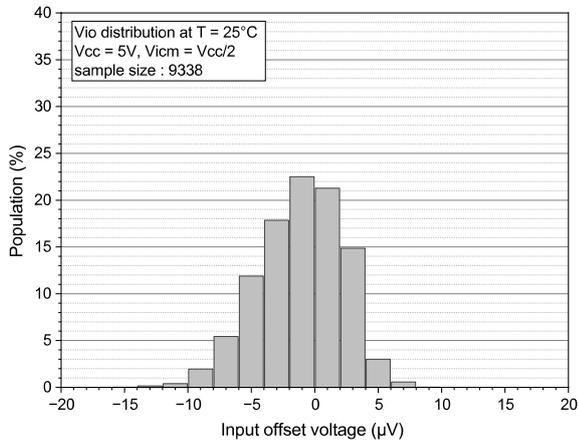
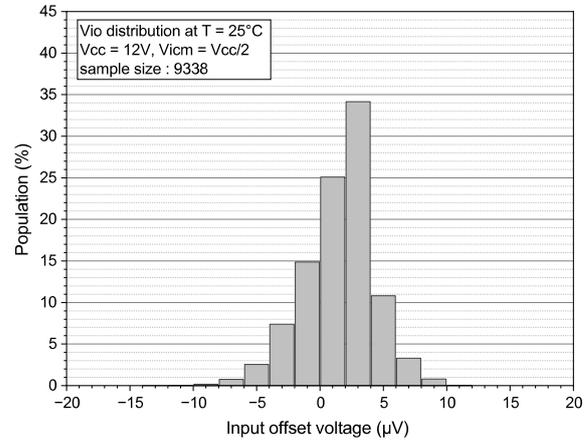
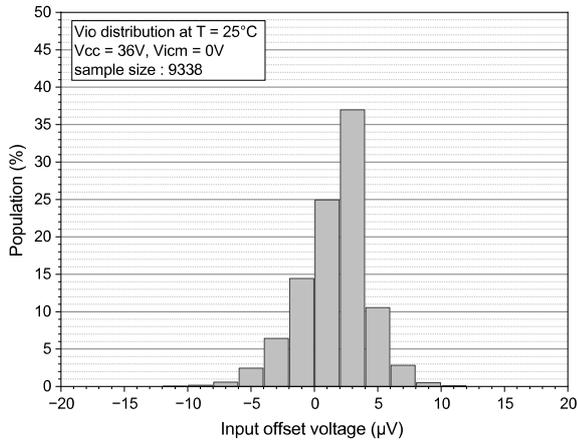
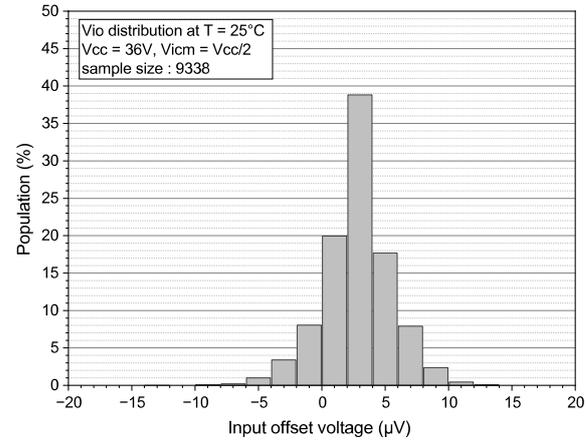
Figure 2. Input offset voltage distribution at $V_{CC} = 5\text{ V}$

Figure 3. Input offset voltage distribution at $V_{CC} = 12\text{ V}$

Figure 4. Input offset voltage distribution at $V_{CC} = 36\text{ V}$ and $V_{icm} = 0\text{ V}$

Figure 5. Input offset voltage distribution at $V_{CC} = 36\text{ V}$ and $V_{icm} = V_{CC}/2$


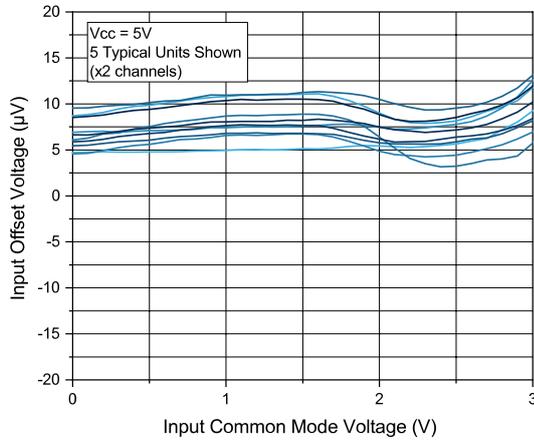
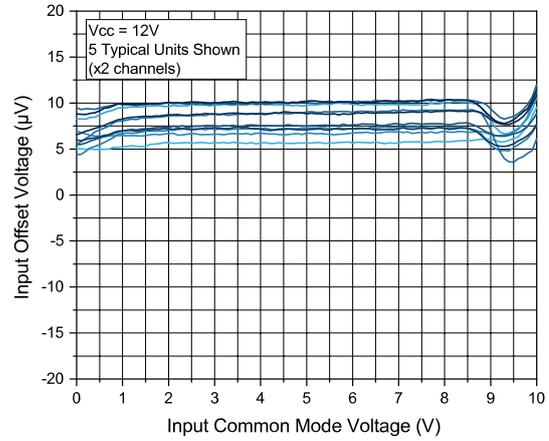
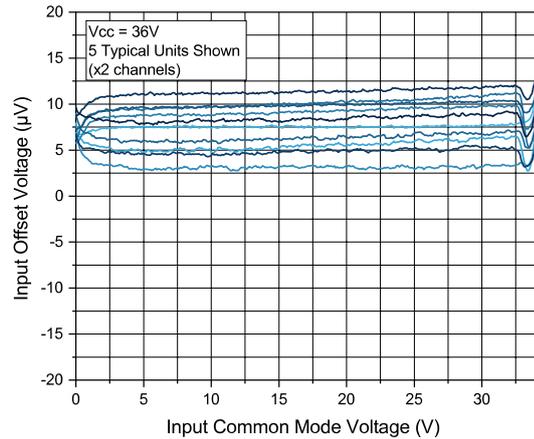
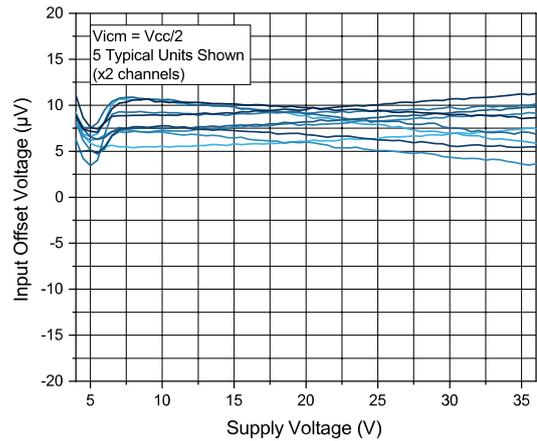
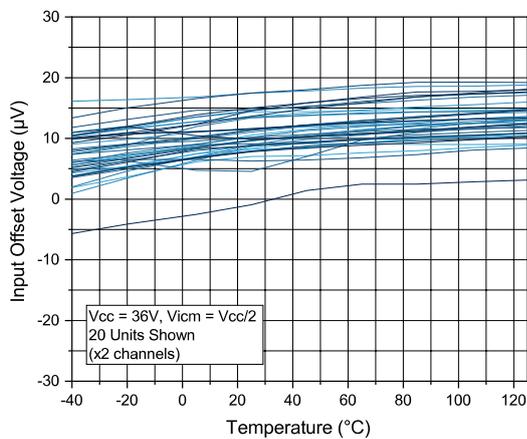
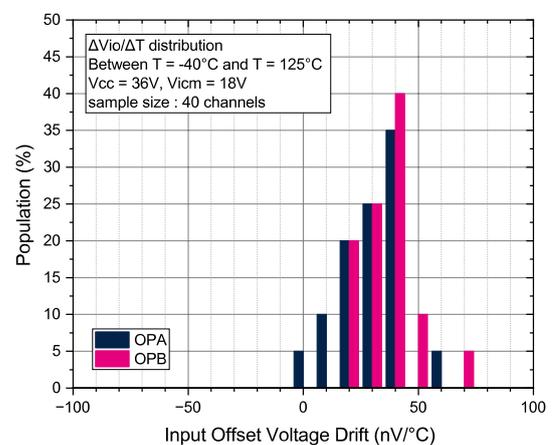
Figure 6. Input offset voltage vs. input common mode voltage at $V_{CC} = 5\text{ V}$

Figure 7. Input offset voltage vs. input common mode voltage at $V_{CC} = 12\text{ V}$

Figure 8. Input offset voltage vs. input common mode voltage at $V_{CC} = 36\text{ V}$

Figure 9. Input offset voltage vs. supply voltage

Figure 10. Input offset voltage vs. temperature

Figure 11. Input offset drift distribution


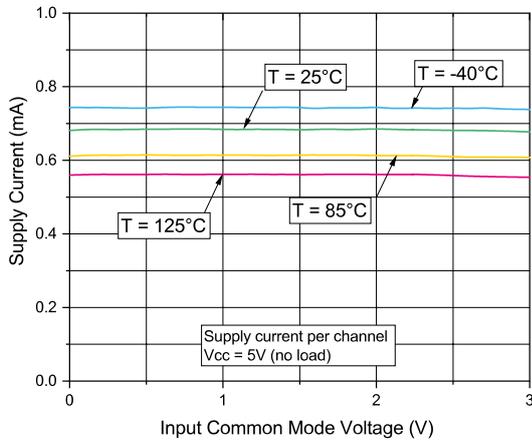
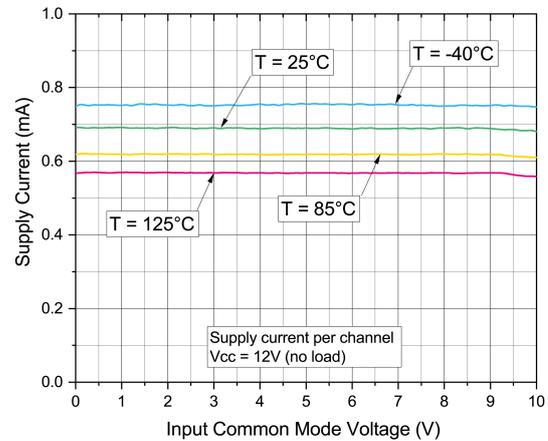
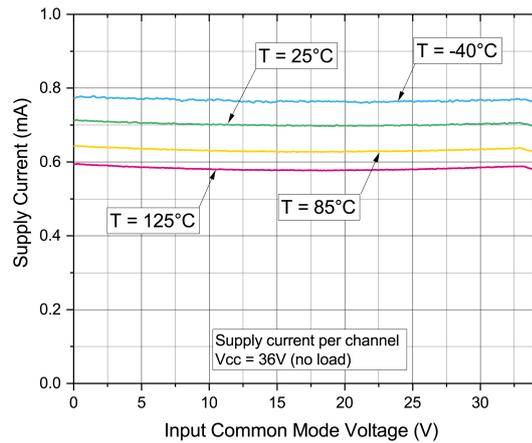
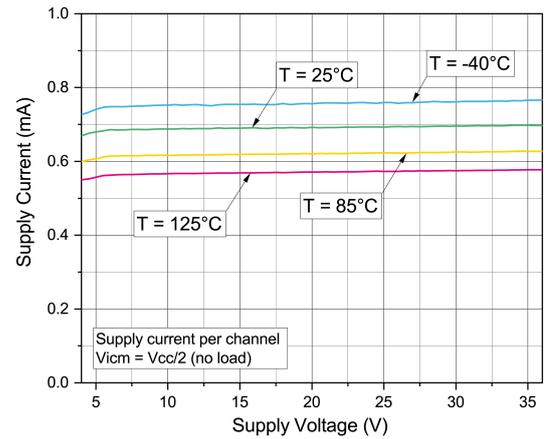
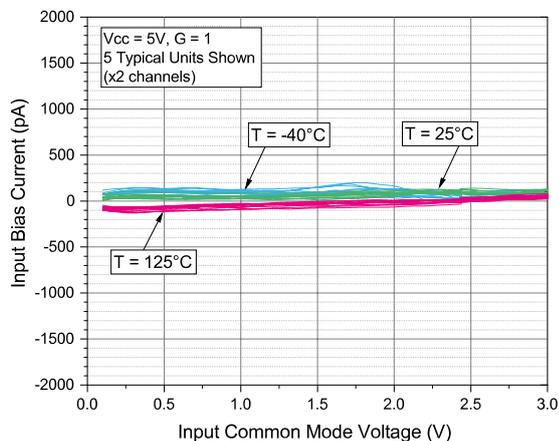
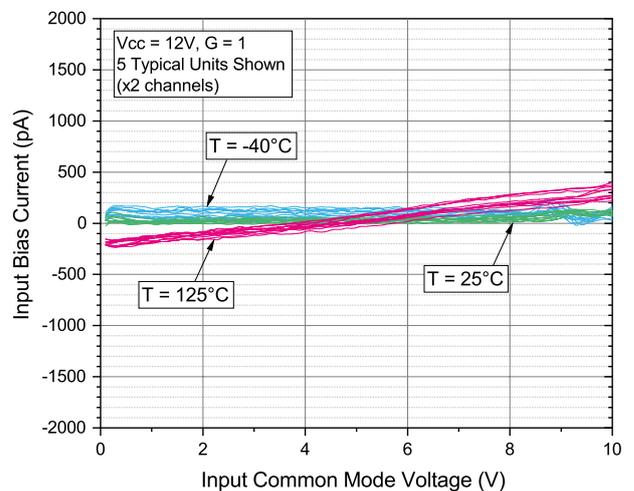
Figure 12. Supply current vs. input common mode voltage at $V_{CC} = 5\text{ V}$

Figure 13. Supply current vs. input common mode voltage at $V_{CC} = 12\text{ V}$

Figure 14. Supply current vs. input common mode voltage at $V_{CC} = 36\text{ V}$

Figure 15. Supply current vs. supply voltage

Figure 16. Input bias current vs. input common mode voltage at $V_{CC} = 5\text{ V}$

Figure 17. Input bias current vs. input common mode voltage at $V_{CC} = 12\text{ V}$


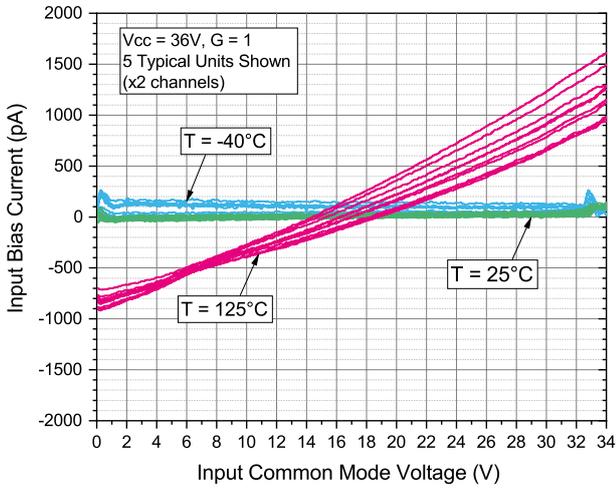
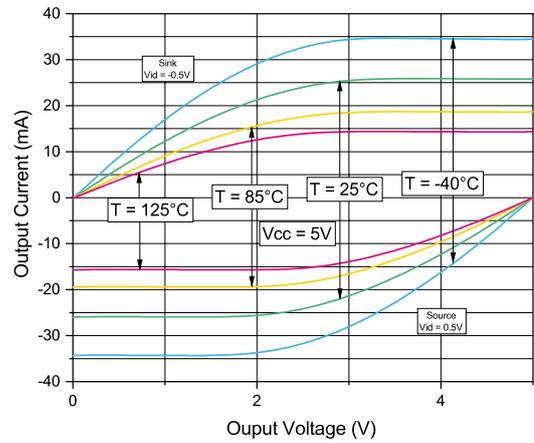
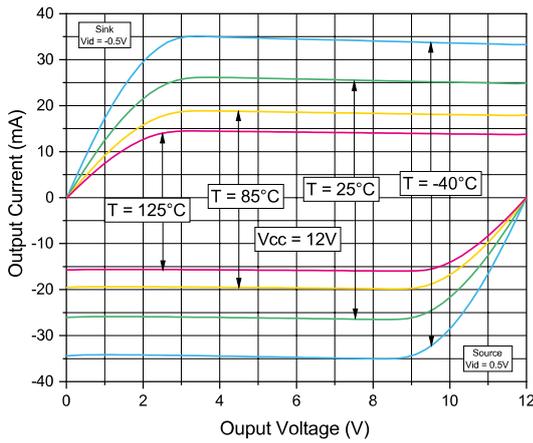
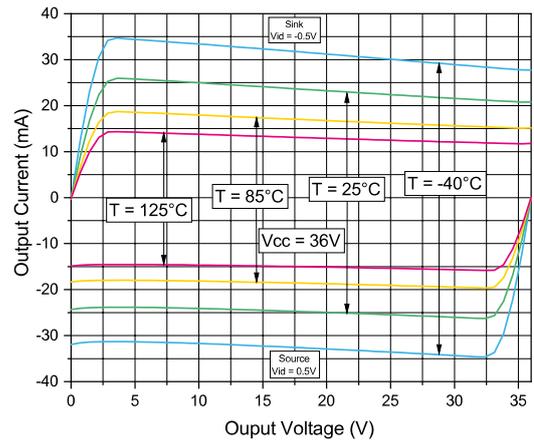
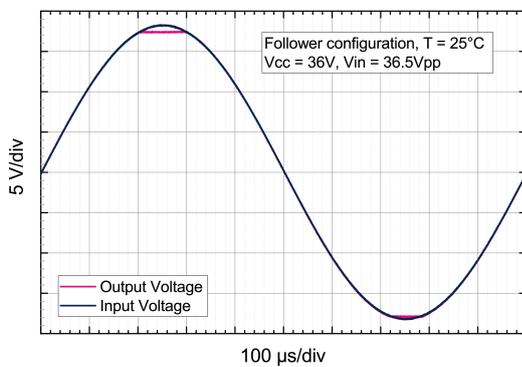
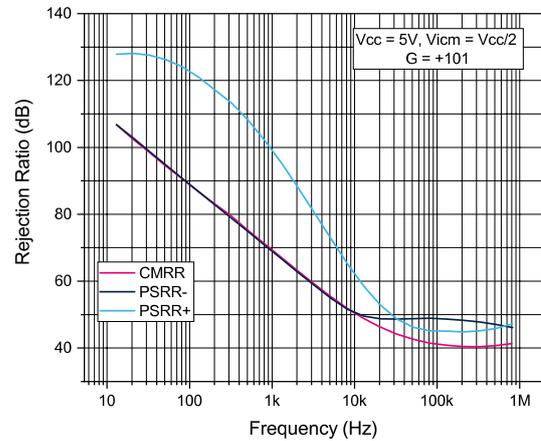
Figure 18. Input bias current vs. input common mode voltage at $V_{CC} = 36\text{ V}$

Figure 19. Output current vs. output voltage at $V_{CC} = 5\text{ V}$

Figure 20. Output current vs. output voltage at $V_{CC} = 12\text{ V}$

Figure 21. Output current vs. output voltage at $V_{CC} = 36\text{ V}$

Figure 22. Output linearity at $V_{CC} = 36\text{ V}$

Figure 23. CMRR and PSRR vs. frequency at $V_{CC} = 5\text{ V}$


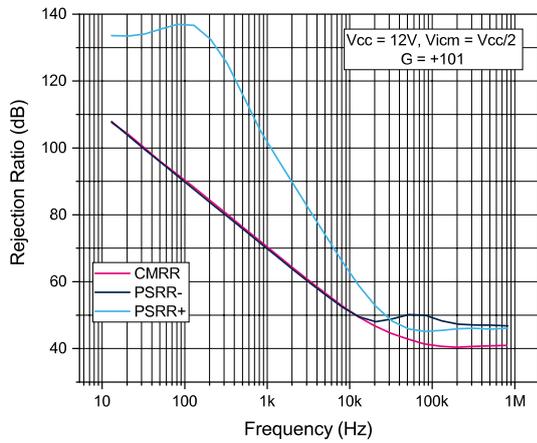
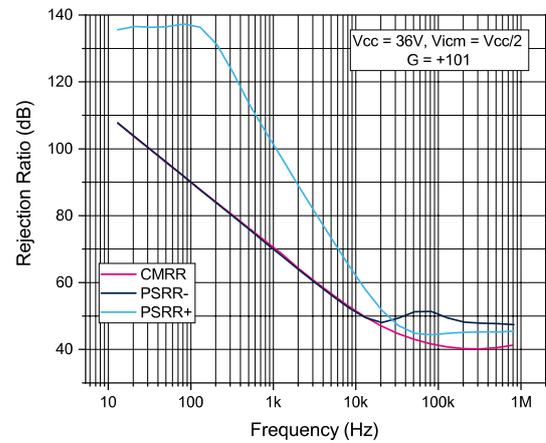
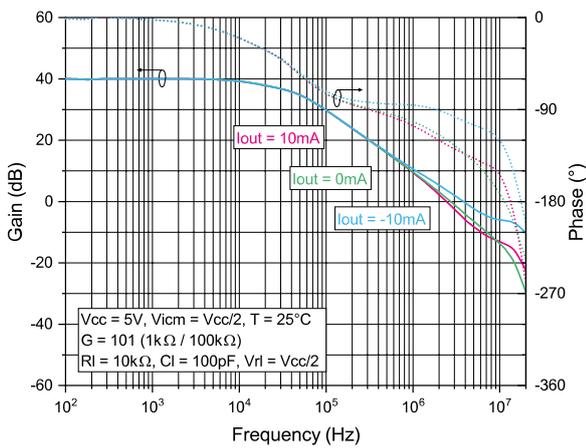
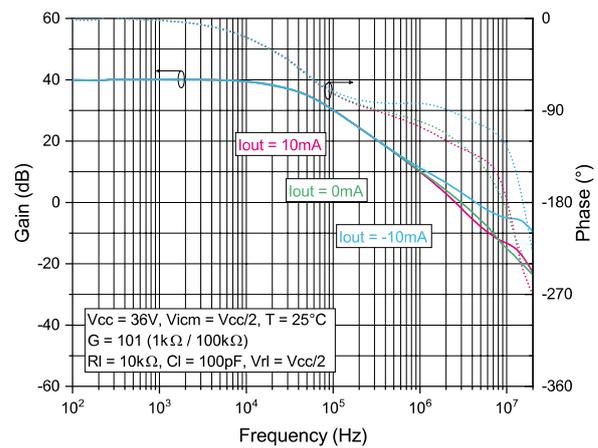
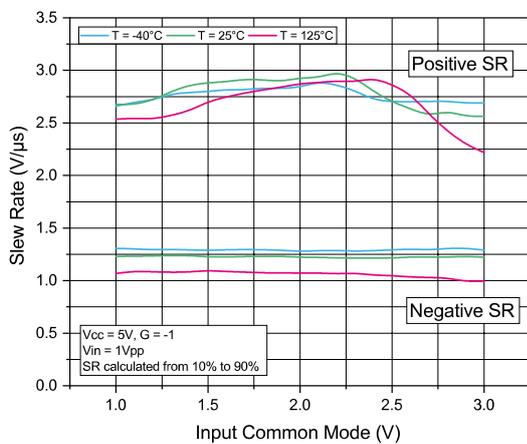
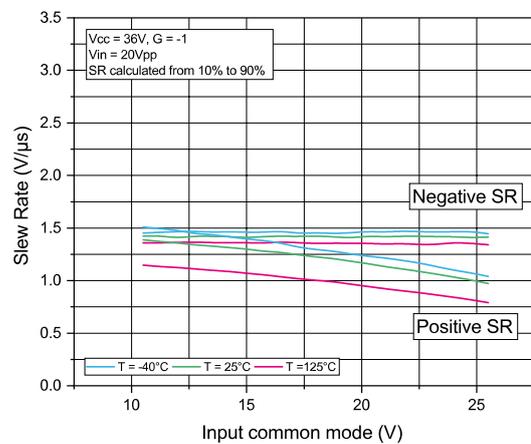
Figure 24. CMRR and PSRR vs. frequency at $V_{CC} = 12\text{ V}$

Figure 25. CMRR and PSRR vs. frequency at $V_{CC} = 36\text{ V}$

Figure 26. Bode plot at $V_{CC} = 5\text{ V}$

Figure 27. Bode plot at $V_{CC} = 36\text{ V}$

Figure 28. Slew rate vs. input common mode voltage at $V_{CC} = 5\text{ V}$

Figure 29. Slew rate vs. input common mode voltage at $V_{CC} = 36\text{ V}$


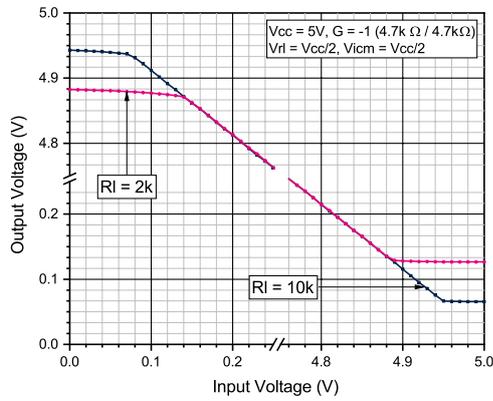
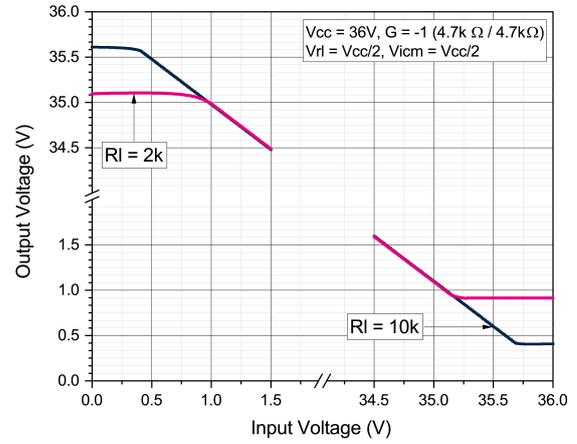
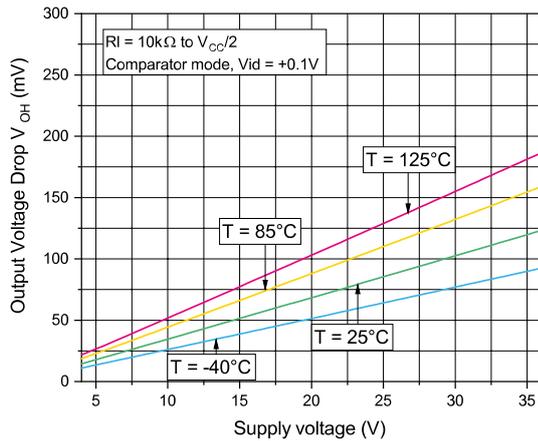
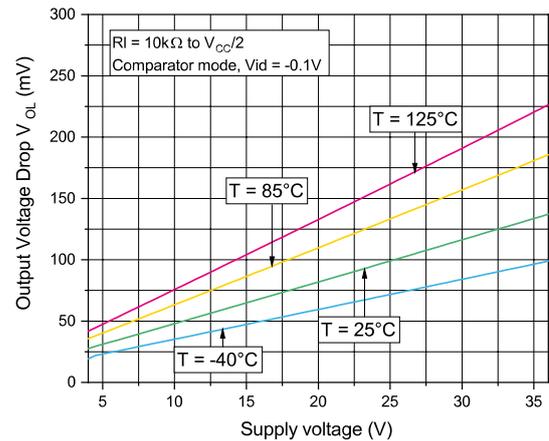
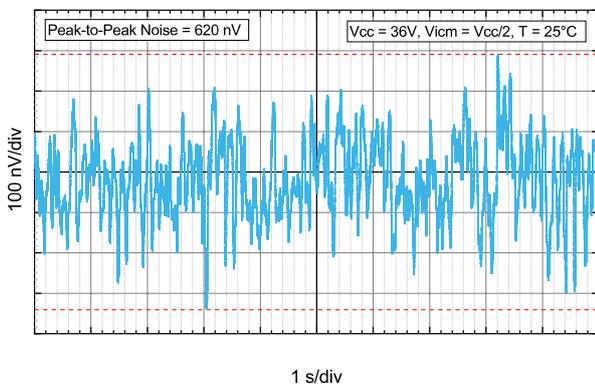
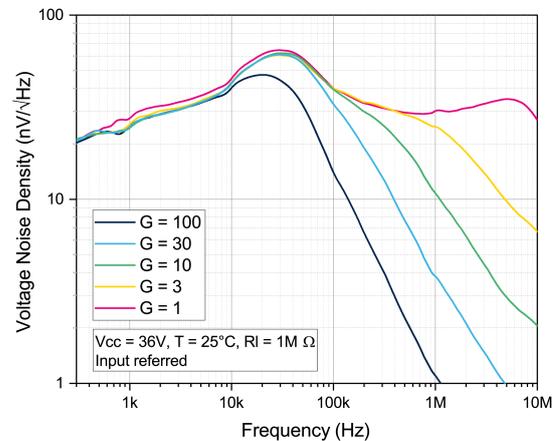
Figure 30. Output voltage vs. input voltage at $V_{CC} = 5\text{ V}$

Figure 31. Output voltage vs. input voltage at $V_{CC} = 36\text{ V}$

Figure 32. Output drop voltage V_{OH} vs. supply voltage

Figure 33. Output drop voltage V_{OL} vs. supply voltage

Figure 34. Noise vs. time at $V_{CC} = 36\text{ V}$

Figure 35. Voltage noise density vs. frequency


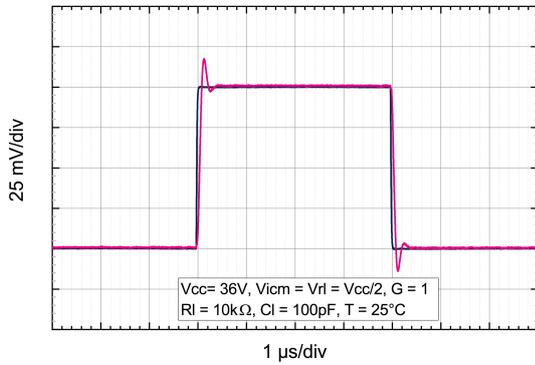
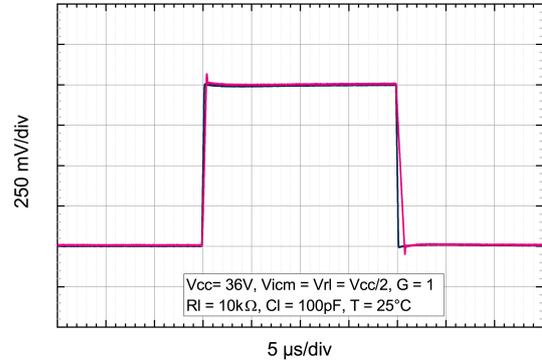
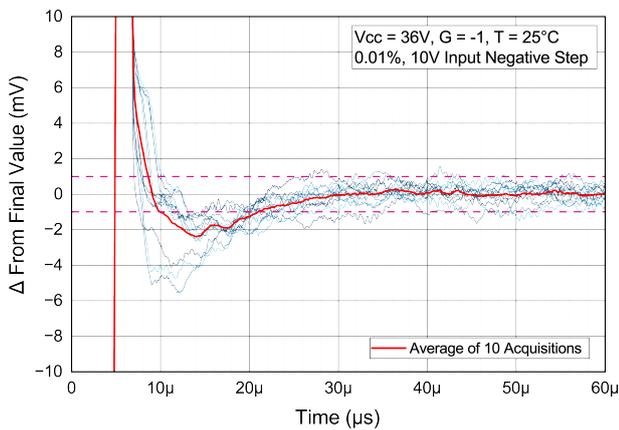
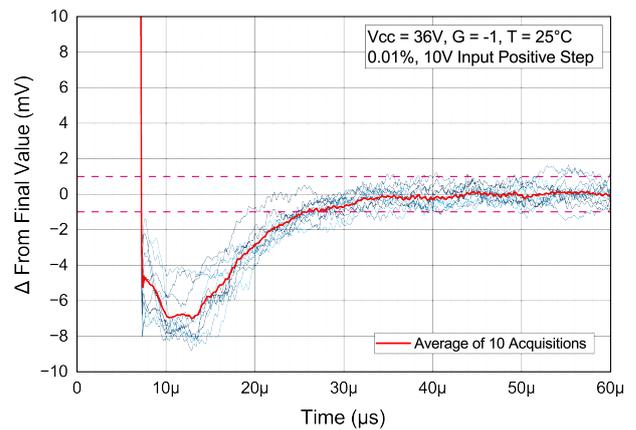
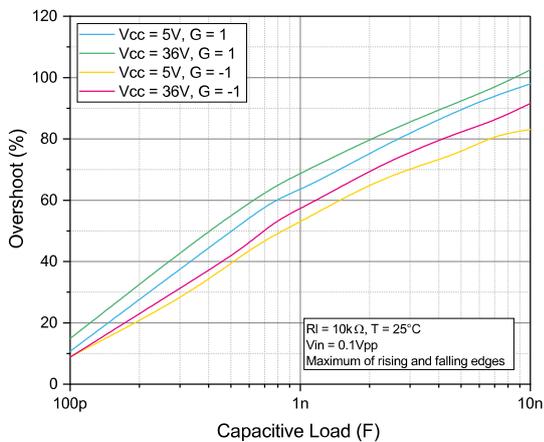
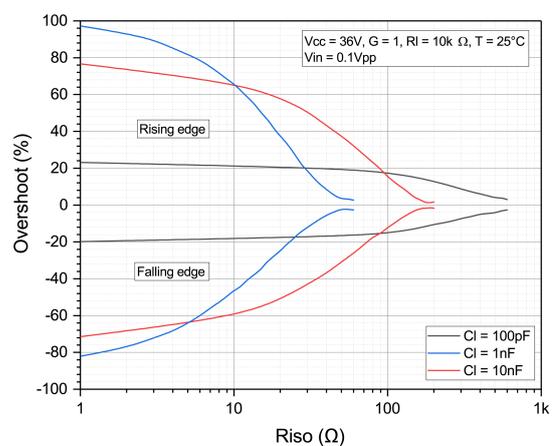
Figure 36. Small signal response at $V_{CC} = 36\text{ V}$

Figure 37. Large signal response at $V_{CC} = 36\text{ V}$

Figure 38. Settling time on negative input step

Figure 39. Settling time on positive input step

Figure 40. Small step overshoot vs. load capacitance

Figure 41. Small step overshoot vs. R_{iso}


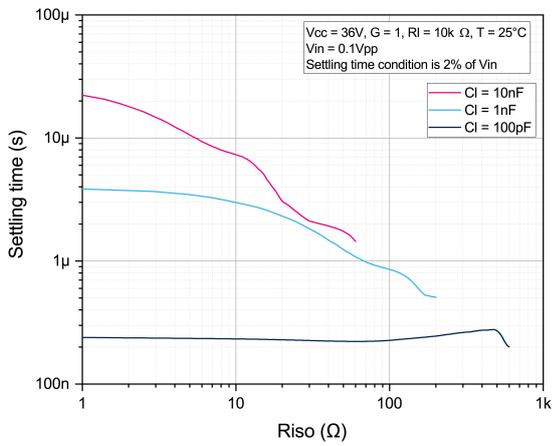
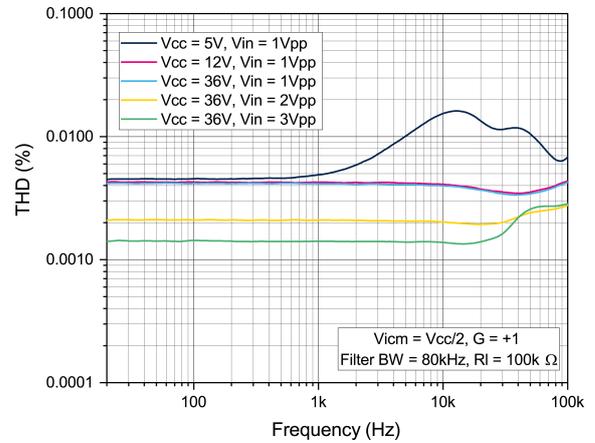
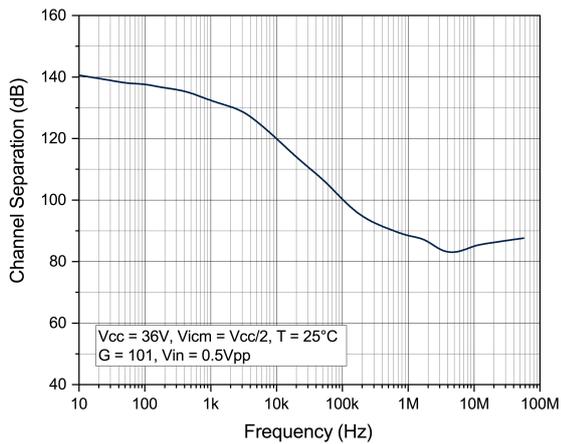
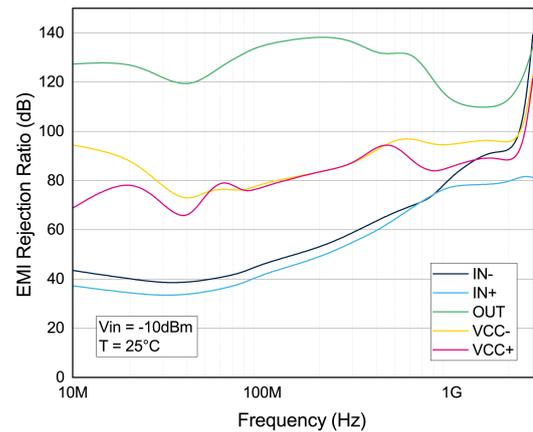
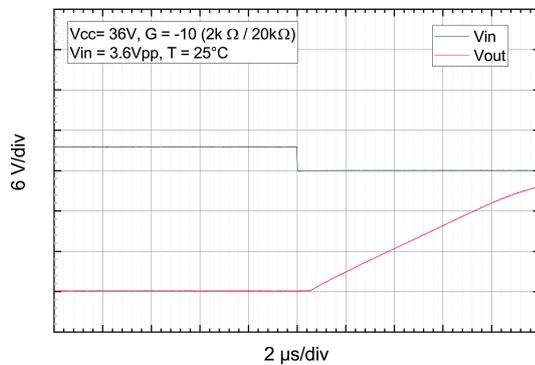
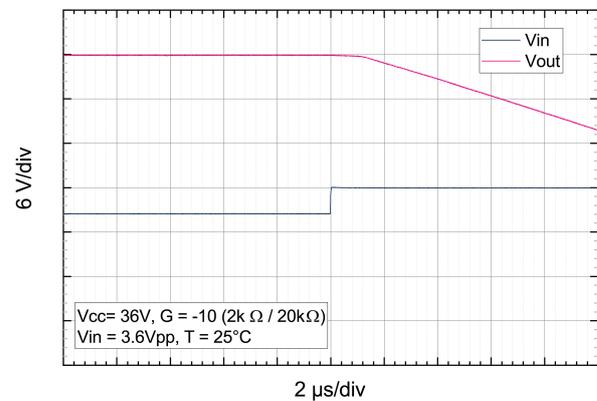
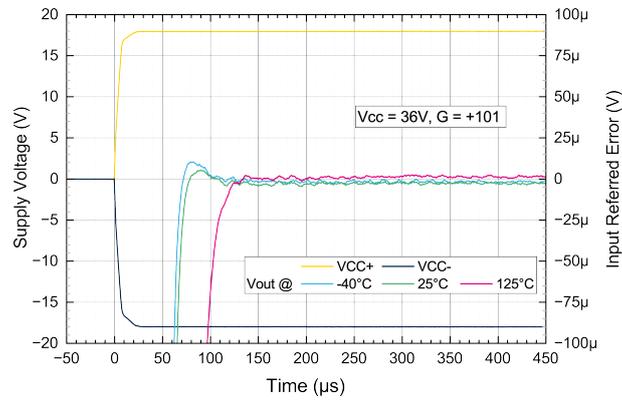
Figure 42. Settling time vs. R_{iso}

Figure 43. THD vs. frequency

Figure 44. Channel separation vs. frequency

Figure 45. EMI rejection vs. frequency

Figure 46. Positive overvoltage recovery

Figure 47. Negative overvoltage recovery


Figure 48. Startup behavior at $V_{CC} = 36\text{ V}$

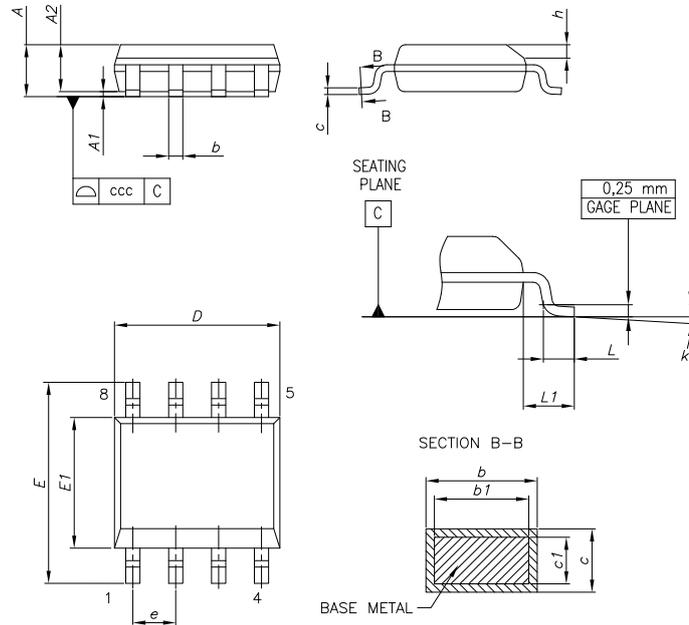


5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

5.1 SO8 package information

Figure 49. SO8 package outline

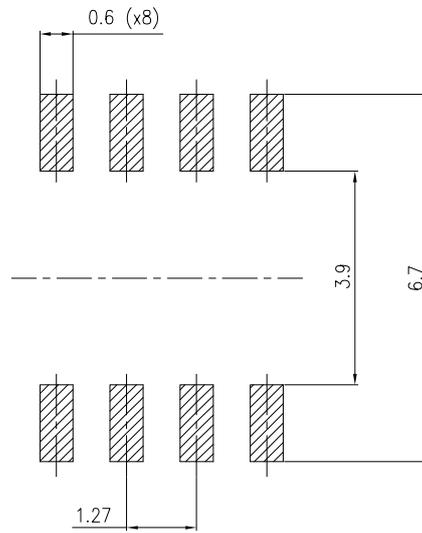


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Table 7. SO8 package mechanical data

Dim	mm		
	Min.	Typ.	Max.
A			1.75
A1	0.10		0.25
A2	1.25		
b	0.31		0.51
b1	0.28		0.48
c	0.10		0.25
c1	0.10		0.23
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e		1.27	
h	0.25		0.50
L	0.40		1.27
L1		1.04	
L2		0.25	
k	0°		8°
ccc			0.10

Figure 50. SO8 recommended footprint



5.2 MiniSO8 package information

Figure 51. MiniSO8 package outline

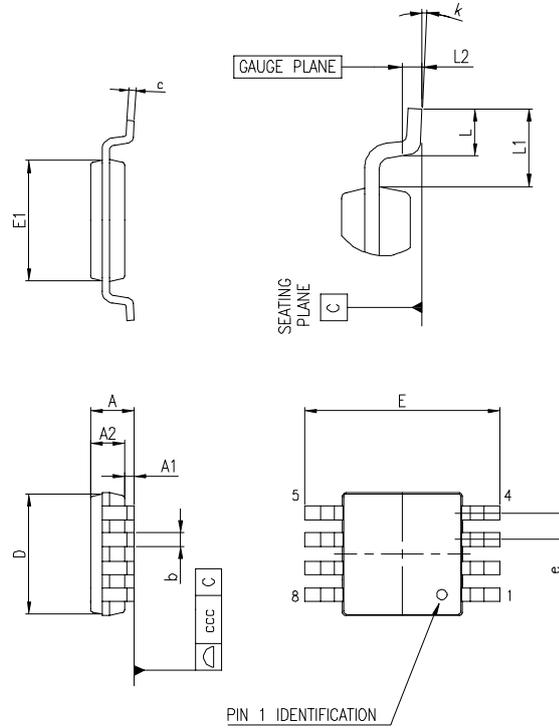
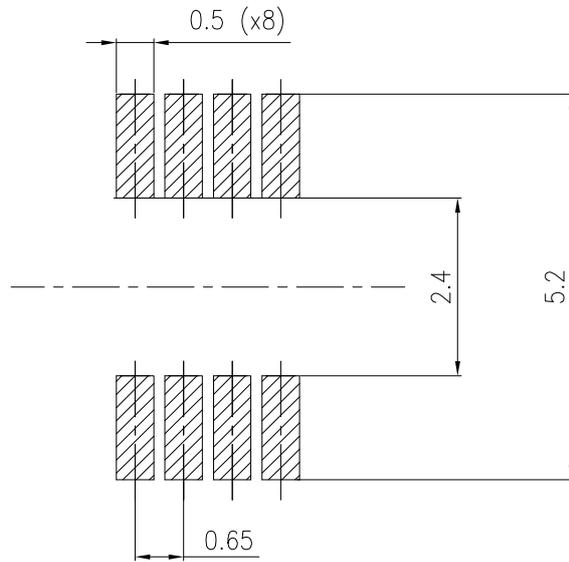


Table 8. MiniSO8 package mechanical data

Dim	mm			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0		0.15	0		0.006
A2	0.75	0.85	0.95	0.03	0.033	0.037
b	0.22		0.4	0.009		0.016
c	0.08		0.23	0.003		0.009
D	2.8	3	3.2	0.11	0.118	0.126
E	4.65	4.9	5.15	0.183	0.193	0.203
E1	2.8	3	3.1	0.11	0.118	0.122
e		0.65			0.026	
L	0.4	0.6	0.8	0.016	0.024	0.031
L1		0.95			0.037	
L2		0.25			0.01	
k	0°		8°	0°		8°
ccc			0.1			0.004

Figure 52. MiniSO8 recommended footprint



6 Ordering information

Table 9. Order code

Order code	Package	Packing	Marking
TSB182IDT	SO8	Tape and reel	TSB182I
TSB182IYDT ⁽¹⁾			TSB182IY
TSB182IST	MiniSO8		K238
TSB182IYST ⁽¹⁾			K239

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent.

Revision history

Table 10. Document revision history

Date	Revision	Changes
07-Jul-2023	1	Initial release.

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